1、General Description

The CD4052 is a dual 4-channel analogue multiplexer/demultiplexer with common channel select logic. Each multiplexer/demultiplexer has four independent inputs/outputs (nY0 to nY3) and a common input/output (nZ). The common channel select logic includes two select inputs (S1 and S2) and an active LOW enable input ($\overline{E}$). Both multiplexers/demultiplexers contain four bidirectional analog switches, each with one side connected to an independent input/output (nY0 to nY3) and the other side connected to a common input/output (nZ). With $\overline{E}$ LOW, one of the four switches is selected (low-impedance ON-state) by S1 and S2. With $\overline{E}$ HIGH, all switches are in the high-impedance OFF-state, independent of S1 and S2. If break before make is needed, then it is necessary to use the enable input.

V_{DD} and V_{SS} are the supply voltage connections for the digital control inputs (S1 and S2, and $\overline{E}$). The V_{DD} to V_{SS} range is 3V to 9V. The analog inputs/outputs (nY0 to nY3, and nZ) can swing between V_{DD} as a positive limit and V_{EE} as a negative limit. V_{DD}-V_{EE} may not exceed 9V. Unused inputs must be connected to V_{DD}, V_{SS}, or another input. For operation as a digital multiplexer/demultiplexer, V_{EE} is connected to V_{SS} (typically ground). V_{EE} and V_{SS} are the supply voltage connections for the switches.

Features:

- Wide supply voltage range from 3V to 9V
- Fully static operation
- 5V and 9V parametric ratings
- Standardized symmetrical output characteristics
- Specified from -40℃ to +85℃
- Packaging information: DIP16/SOP16/TSSOP16

Ordering Information:

Tube packing specifications:

Part number	Packaging form	Marking code	Tube quantity	Boxed tube quantity	Boxed quantity	Notes
CD4052DA16.TB	DIP16	CD4052	25 PCS/tube	40 tube/box	1000 PCS/box	Dimensions of plastic enclosure: 19.0mm×6.4mm Pin spacing: 2.54mm
CD4052SA16.TB	SOP16	CD4052	50 PCS/tube	200 tube/box	10000 PCS/box	Dimensions of plastic enclosure: 10.0mm×3.9mm Pin spacing: 1.27mm
CD4052TA16.TB	TSSOP16	CD4052	96 PCS/tube	200 tube/box	19200 PCS/box	Dimensions of plastic enclosure: 5.0mm×4.4mm Pin spacing: 0.65mm

Reel packing specifications:

Part number	Packaging form	Marking code	Reel quantity	Boxed reel quantity	Notes
CD4052SA16.TR	SOP16(1)	CD4052	2500 PCS/reel	5000 PCS/box	Dimensions of plastic enclosure: 10.0mm×3.9mm Pin spacing:1.27mm
CD4052SA16.TR	SOP16(2)	CD4052	2500 PCS/reel	2500 PCS/box	Dimensions of plastic enclosure: 10.0mm×3.9mm Pin spacing:1.27mm
CD4052TA16.TR	TSSOP16	CD4052	2500 PCS/reel	5000 PCS/box	Dimensions of plastic enclosure: 5.0mm×4.4mm Pin spacing:0.65mm

Note: If the physical information is inconsistent with the ordering information, please refer to the actual product.

2、Block Diagram And Pin Description

2.1、Block Diagram

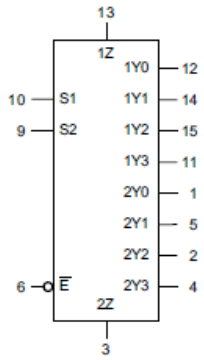


Figure 1. Logic symbol

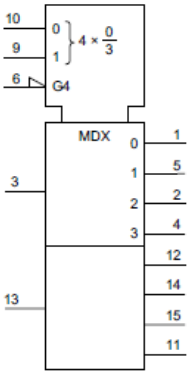


Figure 2. IEC logic symbol

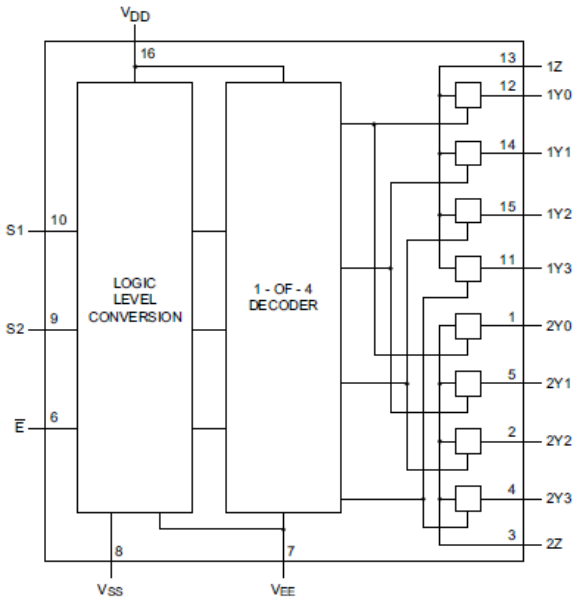


Figure 3. Functional diagram

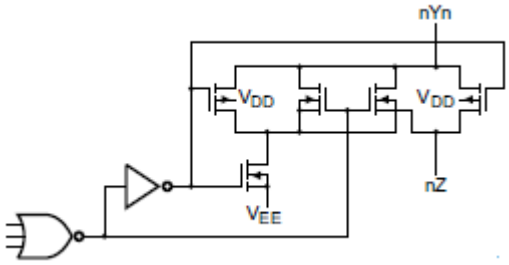


Figure 4. Schematic diagram (one switch)

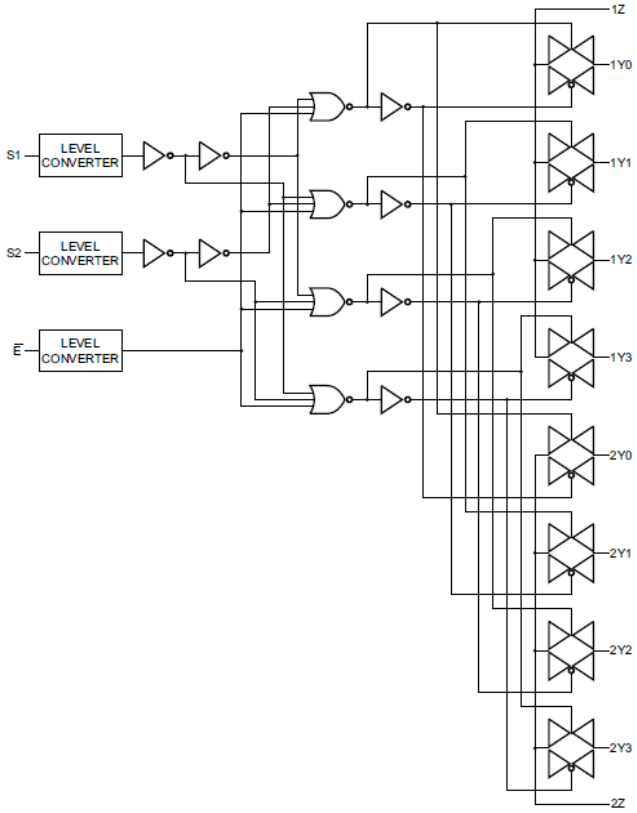
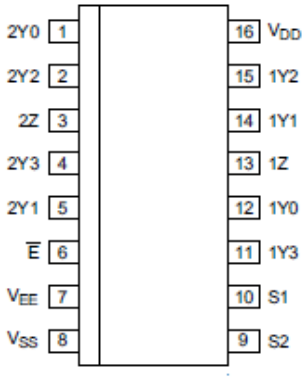


Figure 5. Logic diagram

2.2、Pin Configurations



2.3、Pin Description

Pin No.	Pin Name	Description
1	2Y0	independent input or output
2	2Y2	independent input or output
3	2Z	common output or input
4	2Y3	independent input or output
5	2Y1	independent input or output
6	$\overline{E}$	enable input (active LOW)
7	V_{EE}	supply voltage
8	V_{SS}	ground (0V)
9	S2	select input
10	S1	select input
11	1Y3	independent input or output
12	1Y0	independent input or output
13	1Z	common output or input
14	1Y1	independent input or output
15	1Y2	independent input or output
16	V_{DD}	supply voltage

2.4、Function Table

Input			Channel ON
$\overline{E}$	S2	S1	
L	L	L	nY0 to nZ
L	L	H	nY1 to nZ
L	H	L	nY2 to nZ
L	H	H	nY3 to nZ
H	X	X	switches off

Note: H=HIGH voltage level; L=LOW voltage level; X=don’t care.

3、Electrical Parameter

3.1、Absolute Maximum Ratings

(Voltages are referenced to V_{SS} (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Max.	Unit
supply voltage	V_{DD}	-		-0.5	+12	V
power supply range	V_{DD}-V_{EE}	-		-0.5	+12	V
static current	I_Q	V_{DD}-V_{EE}=12V		-	2	uA
input voltage	V_I	-		-0.5	V_{DD}+0.5	V
output high voltage current	$\|I_{IH}\|$	V_{DD}=5V, V_I=V_{DD}		-	1	uA
output low voltage current	$\|I_{IL}\|$	V_{DD}=5V, V_I=0V		-	1	uA
input and output voltage rage	V_{IO}	-		V_{EE}-0.5	V_{DD}+0.5	V
input clamping current	I_{IK}	V_I<-0.5V or V_I>V_{DD}+0.5V		-	±20	mA
input and output clamp current	I_{IOK}	V_{IO}<V_{EE}-0.5V or V_{IO}>V_{DD}+0.5V		-	±20	mA
switch conduction current	I_T	V_O=-0.5V to V_{DD}+0.5V		-	±25	mA
VDD or GND current	I_{DD}, I_{GND}	-		-	±50	mA
storage temperature	T_{stg}	-		-65	+150	℃
total power dissipation	P_{tot}	-		-	500	mW
Soldering temperature	T_L	10s	DIP	245		℃
			SOP	250		℃

Note:

[1] For DIP16 packages: above 70℃ the value of P_{tot} derates linearly with 12mW/K.

[2] For SOP16 packages: above 70℃ the value of P_{tot} derates linearly with 8mW/K.

[3] For (T)SSOP16 packages: above 60℃ the value of P_{tot} derates linearly with 5.5mW/K.

3.2、Recommended Operating Conditions

(T_{amb}=25℃; R_L=10kΩ; C_L=50pF; $\overline{E}$=V_{DD}; Vis=V_{DD}=5V.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
supply voltage	V_{DD}	-	3	5	9	V
ambient temperature	T_{amb}	in free air	-40	-	+85	℃
supply voltage	V_{EE}	-	-6.0	-	0	V
supply voltage	V_{DD}-V_{EE}	-	3.0	-	9.0	V
input voltage	V_I	-	0	-	V_{DD}	V
input and output voltage	V_{IO}	-	V_{EE}	-	V_{DD}	V
Input rise and fall time	t_r, t_f	-	-	-	1000	ns
		-	-	-	500	ns
		-	-	-	400	ns
input capacitance	C_I	-	-	-	7.5	pF

3.3、Electrical Characteristics

3.3.1、DC Characteristics 1

(T_{amb}=25℃, voltages are referenced to V_{SS} (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions (V)		T_{amb}=25℃			Unit
				Min.	Typ.	Max.	
supply current	I_{DD}	V_I=V_{DD} or V_{SS}, I_O=0A	V_{DD}=5V	-	-	20	uA
			V_{DD}=9V	-	-	40	uA
HIGH-level input voltage	V_{IH}	|I_O|<1uA	V_{DD}=5V, V_O=0.5V or 4.5V	3.5	-	-	V
			V_{DD}=9V, V_O=0.5V or 8V	7.0	-	-	V
LOW-level input voltage	V_{IL}	|I_O|<1uA	V_{DD}=5V, V_O=0.5V or 4.5V	-	-	1.5	V
			V_{DD}=9V, V_O=0.5V or 8V	-	-	3.0	V
input leakage current	I_I	V_I=0V or 9V, V_{DD}=9V		-	-	0.3	uA
3 state output leakage current	I_{OZ}	V_{DD}=9V	output to V_{DD}	-	-	1.6	uA
			output to V_{SS}	-	-	-1.6	uA
ON resistance (rail)	R_{ON}	V_I=0V to V_{DD}-V_{EE}	V_{DD}-V_{EE}=5V	-	350	2500	Ω
			V_{DD}-V_{EE}=9V	-	80	245	Ω
		V_I=0V	V_{DD}-V_{EE}=5V	-	115	340	Ω
			V_{DD}-V_{EE}=9V	-	50	160	Ω
		V_I=V_{DD}-V_{EE}	V_{DD}-V_{EE}=5V	-	120	365	Ω
			V_{DD}-V_{EE}=9V	-	65	200	Ω
ON resistance mismatch between channels	ΔR_{ON}	V_I=0V to V_{DD}-V_{EE}	V_{DD}-V_{EE}=5V	-	25	-	Ω
			V_{DD}-V_{EE}=9V	-	10	-	Ω
OFF-state leakage current	$I_{S(OFF)}$	V_{SS}=V_{EE}, V_{DD}-V_{EE}=9V	all channel off; $\overline{E}$=V_{DD}	-	-	1000	nA
			any channel; $\overline{E}$=V_{SS}	-	-	200	nA

Note: On resistance waveform and test circuit see Figure 13 and Figure 14.

3.3.2、DC Characteristics 2

(T_{amb}=-40℃ to +85℃, voltages are referenced to V_{SS} (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions (V)		T_{amb}=-40℃		T_{amb}=+85℃		Unit
				Min.	Max.	Min.	Max.	
supply current	I_{DD}	V_I=V_{DD} or V_{SS}, I_O=0A	V_{DD}=5V	-	20	-	150	uA
			V_{DD}=9V	-	40	-	300	uA
HIGH-level input voltage	V_{IH}	|I_O|<1uA	V_{DD}=5V, V_O=0.5V or 4.5V	3.5	-	3.5	-	V
			V_{DD}=9V, V_O=0.5V or 8V	7.0	-	7.0	-	V
LOW-level input voltage	V_{IL}	|I_O|<1uA	V_{DD}=5V, V_O=0.5V or 4.5V	-	1.5	-	1.5	V
			V_{DD}=9V, V_O=0.5V or 8V	-	3.0	-	3.0	V

input leakage current	I_I	V_I=0V or 9V, V_{DD}=9V		-	0.3	-	1.0	uA
3 state output leakage current	I_{OZ}	V_{DD}=9V	output to V_{DD}	-	1.6	-	12.0	uA
			output to V_{SS}	-	-1.6	-	-12.0	uA

3.3.3、AC Characteristics 1

(T_{amb}=25℃, V_{EE}=V_{SS}=0V, t_r, t_f≤20ns, C_L=50pF, R_L=10kΩ, unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
HIGH to LOW propagation delay time	t_{PHL}	Yn to Z; Z to Yn; see Figure 7	V_{DD}=5V	-	10	20	ns
			V_{DD}=9V	-	5	10	ns
		Sn to Yn, Z; see Figure 8	V_{DD}=5V	-	150	305	ns
			V_{DD}=9V	-	65	135	ns
LOW to HIGH propagation delay	t_{PLH}	Yn to Z; Z to Yn; see Figure 7	V_{DD}=5V	-	10	20	ns
			V_{DD}=9V	-	5	10	ns
		Sn to Yn, Z; see Figure 8	V_{DD}=5V	-	150	300	ns
			V_{DD}=9V	-	75	150	ns
HIGH to OFF-state propagation delay	t_{PHZ}	$\overline{E}$ to Yn, Z; see Figure 9	V_{DD}=5V	-	95	190	ns
			V_{DD}=9V	-	90	180	ns
LOW to OFF-state propagation delay	t_{PLZ}	$\overline{E}$ to Yn, Z; see Figure 9	V_{DD}=5V	-	100	205	ns
			V_{DD}=9V	-	90	180	ns
OFF-state to HIGH propagation delay	t_{PZH}	$\overline{E}$ to Yn, Z; see Figure 9	V_{DD}=5V	-	130	260	ns
			V_{DD}=9V	-	55	115	ns
OFF-state to LOW propagation delay	t_{PZL}	$\overline{E}$ to Yn, Z; see Figure 9	V_{DD}=5V	-	120	240	ns
			V_{DD}=9V	-	50	100	ns

3.3.4、AC Characteristics 2

(T_{amb}=25℃, V_{EE}=V_{SS}=0V, V_I=0.5V_{DD} (p-p), unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
Square wave distortion	d_{sin}	see Figure 10; R_L=10kΩ; C_L=15pF; channel ON; f_i=1kHz	V_{DD}=5V	0.25	-	-	%
			V_{DD}=9V	0.04	-	-	%
any two channel crosstalk	f_{ct}	V_{DD}=9V, see note2		1	-	-	MHz
crosstalk voltage ($\overline{E}$ to Sn or Yn to Z)	V_{ct}	see Figure 11; R_L=10kΩ; C_L=15pF; $\overline{E}$ or Sn=V_{DD} (square-wave)		50	-	-	mV
OFF frequency	f_{OFF}	V_{DD}=9V, see note3		1	-	-	MHz
conduction frequency	f_{ON}	V_{DD}=5V, see note4		13	-	-	MHz
		V_{DD}=9V, see note4		40	-	-	MHz

Note:

[1] f_i is biased at 0.5V_{DD}; V_I=0.5V_{DD} (p-p).

[2] R_L=1kΩ; 20logVos/Vis=-50dB, see Figure 12.

[3] R_L=1kΩ; C_L=5pF, channel off, 20logVos/Vis=-50dB, see Figure 10.

[4] R_L=1kΩ; C_L=5pF, channel on, 20logVos/Vis=-3dB, see Figure 10.

4、Testing Circuit

4.1、AC Testing Circuit 1

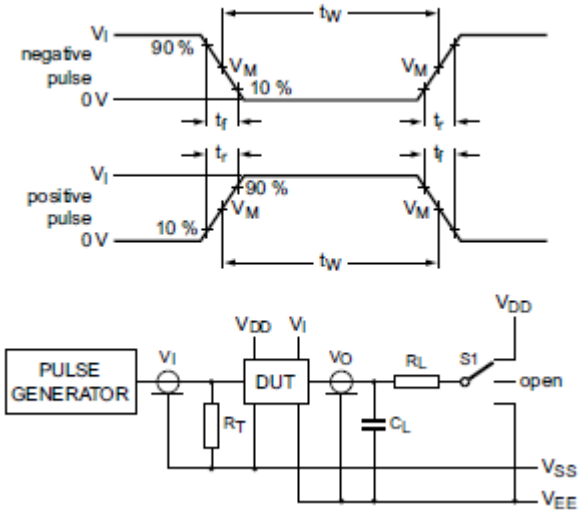


Figure 6. Test circuit for switching times

Definitions for test circuit:

DUT=Device Under Test.

C_L=Load capacitance including jig and probe capacitance.

R_T=Termination resistance should be equal to the output impedance Z_o of the pulse generator.

R_L=Load resistance.

4.2、AC Testing Waveforms

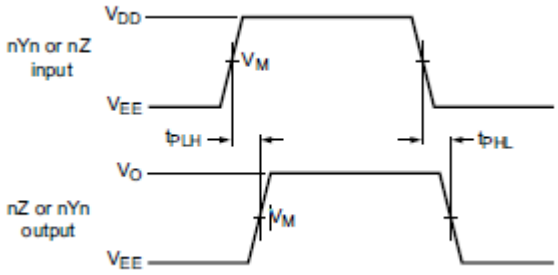


Figure 7. nYn, nZ to nZ, nYn propagation delays

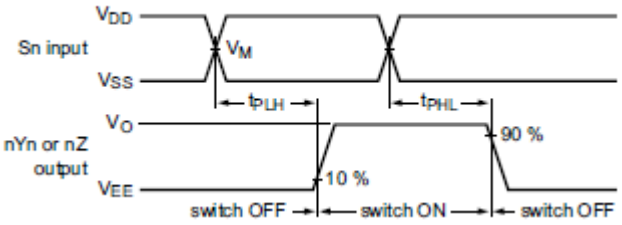


Figure 8. Sn to nYn, nZ propagation delays

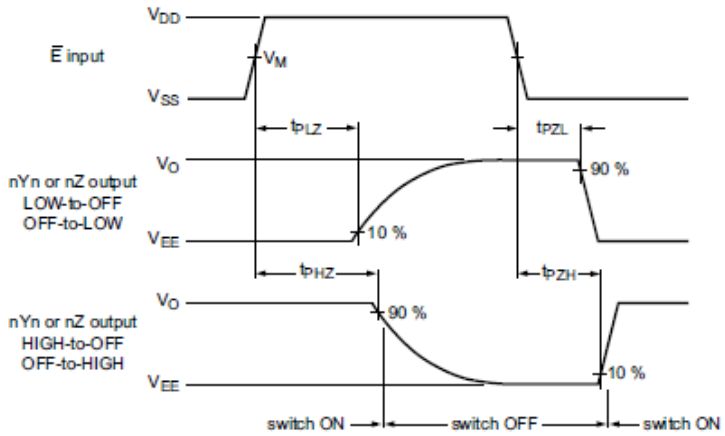


Figure 9. Enable and disable times

4.3、AC Testing Circuit 2

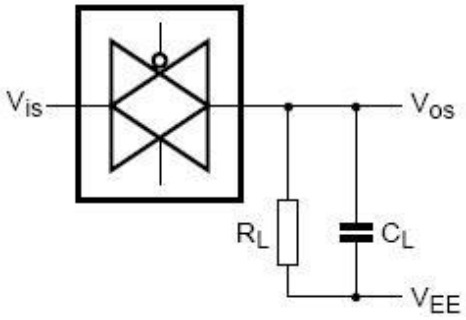


Figure 10. Square wave distortion degree of cut-off frequency and conduction frequency test pattern

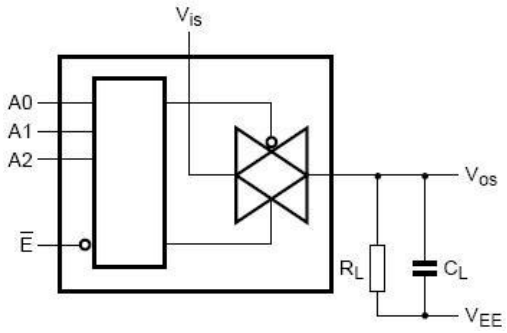


Figure 11. Crosstalk logical input/output test

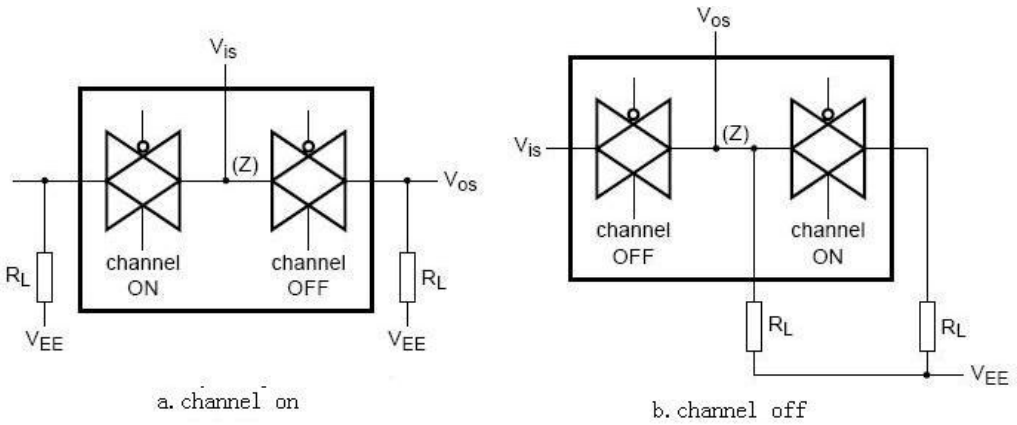


Figure 12. Inter channel Crosstalk

4.4、On Resistance Waveform And Test Circuit

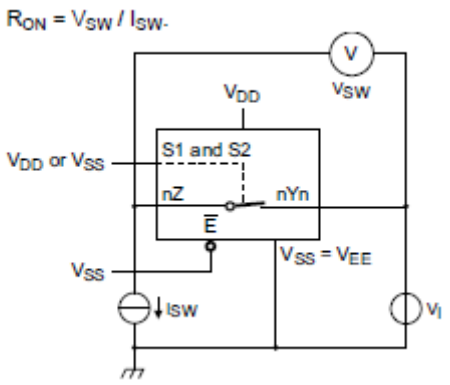


Figure 13. Test circuit for measuring R_{ON}

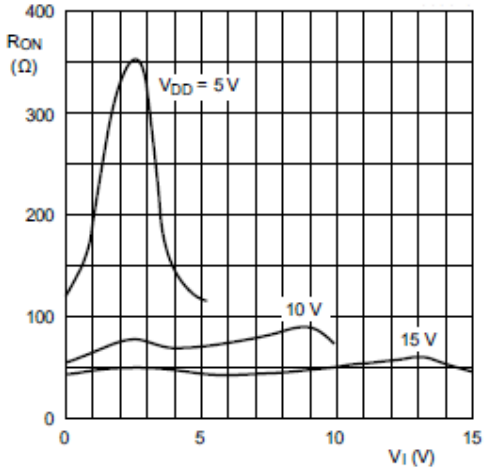


Figure 14. Typical R_{ON} as a function of input voltage

4.5、Measurement Points

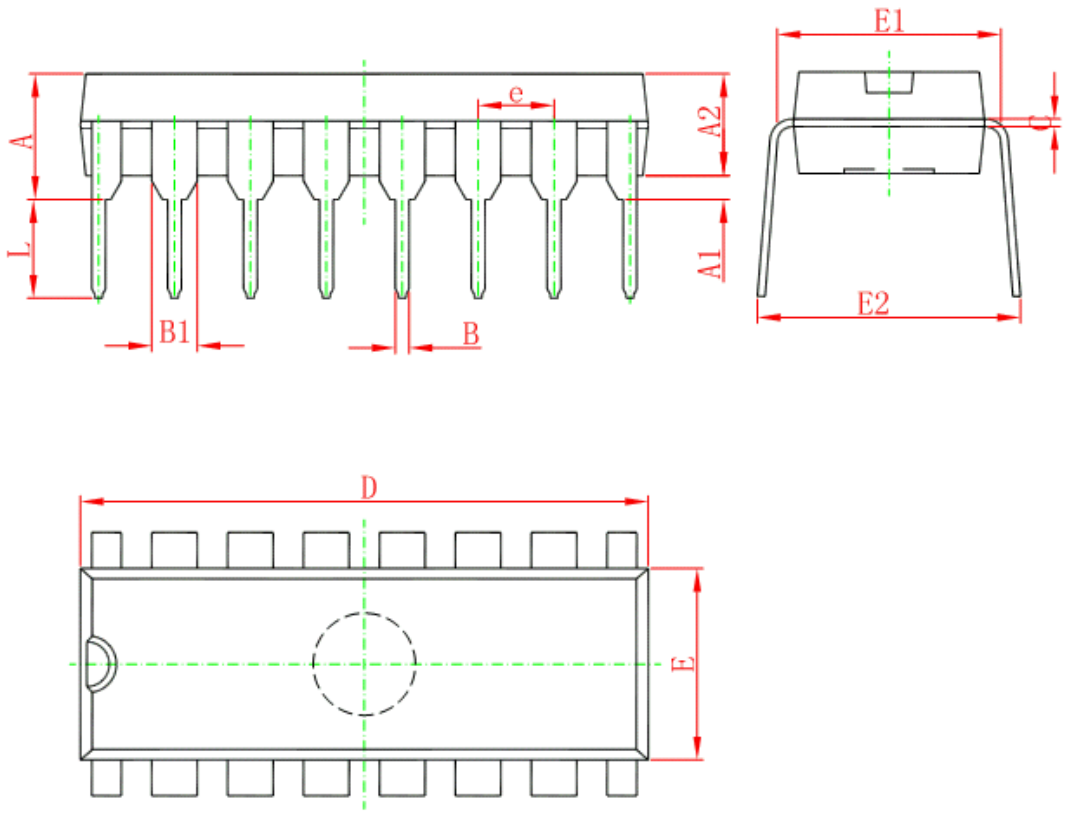
Supply voltage	Input	Output
V_{DD}	V_M	V_M
3V to 9V	$0.5\times V_{DD}$	$0.5\times V_{DD}$

4.6、Test Data

Test	Input		Load		Switch
	V_{is}	t_r, t_f	C_L	R_L	
t_{PHL}	V_{EE}	20ns	50pF	10kΩ	V_{DD}
t_{PLH}	V_{DD}	20ns	50pF	10kΩ	V_{EE}
t_{PZH}, t_{PHZ}	V_{DD}	20ns	50pF	10kΩ	V_{EE}
t_{PZL}, t_{PLZ}	V_{EE}	20ns	50pF	10kΩ	V_{DD}
others	pulse	20ns	50pF	10kΩ	open

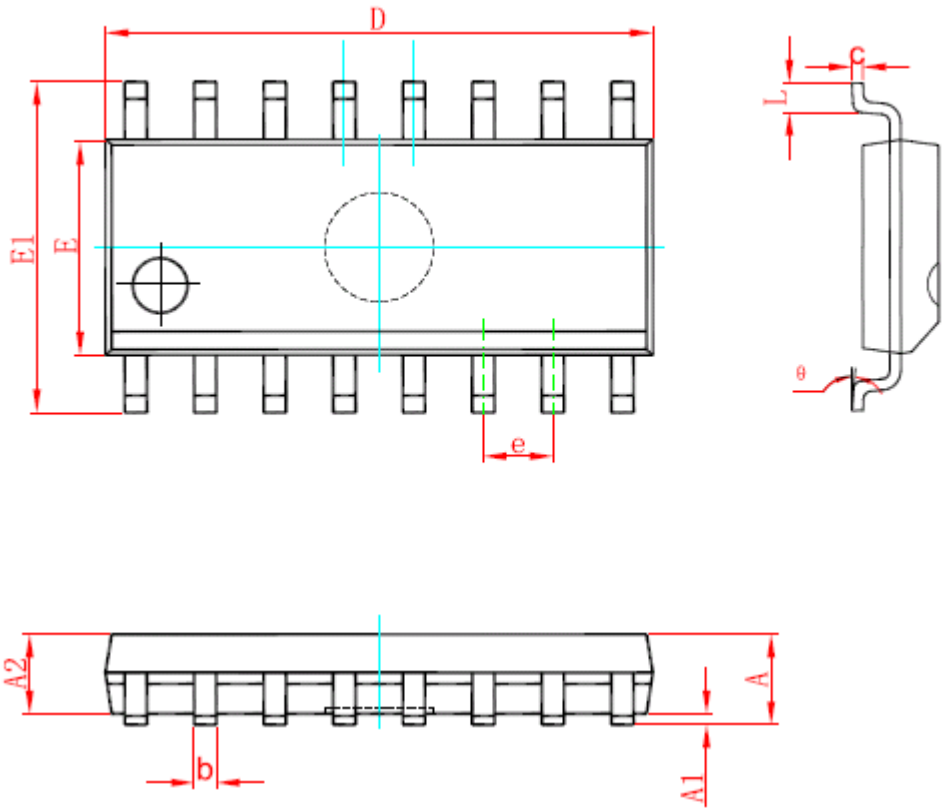
5、Package Information

5.1、DIP16



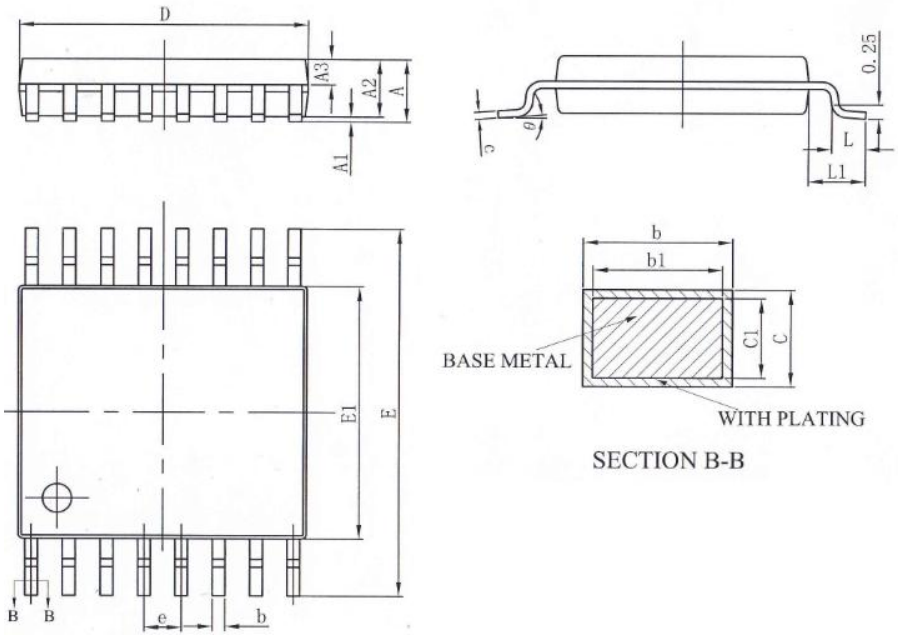
Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	3.710	4.310	0.146	0.170
A1	0.510		0.020	
A2	3.200	3.600	0.126	0.142
B	0.380	0.570	0.015	0.022
B1	1.524(BSC)		0.060(BSC)	
C	0.204	0.360	0.008	0.014
D	18.800	19.200	0.740	0.756
E	6.200	6.600	0.244	0.260
E1	7.320	7.920	0.288	0.312
e	2.540(BSC)		0.100(BSC)	
L	3.000	3.600	0.118	0.142
E2	8.400	9.000	0.331	0.354

5.2、SOP16



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.007	0.010
D	9.800	10.200	0.386	0.402
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
e	1.270(BSC)		0.050(BSC)	
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

5.3、TSSOP16



SYMBOL	MILLIMETER		
	MIN	NOM	MAX
A	—	—	1.20
A1	0.05	—	0.15
A2	0.90	1.00	1.05
A3	0.39	0.44	0.49
b	0.20	—	0.28
b1	0.19	0.22	0.25
c	0.13	—	0.17
c1	0.12	0.13	0.14
D	4.90	5.00	5.10
E	6.20	6.40	6.60
E1	4.30	4.40	4.50
e	0.65BSC		
L	0.45	0.60	0.75
L1	1.00BSC		
θ	0	—	8°

6、Statements And Notes

6.1、The name and content of Hazardous substances or Elements in the product

Part name	Hazardous substances or Elements									
	Lead and lead compounds	Mercury and mercury compounds	Cadmium and cadmium compounds	Hexavalent chromium compounds	Polybrominated biphenyls	Polybrominated biphenyl ethers	Dibutyl phthalate	Butylbenzyl phthalate	Di-2-ethylhexyl phthalate	Diisobutyl phthalate
Lead frame	○	○	○	○	○	○	○	○	○	○
Plastic resin	○	○	○	○	○	○	○	○	○	○
Chip	○	○	○	○	○	○	○	○	○	○
The lead	○	○	○	○	○	○	○	○	○	○
Plastic sheet installed	○	○	○	○	○	○	○	○	○	○
explanation	○：Indicates that the content of hazardous substances or elements in the detection limit of the following the SJ/T11363-2006 standard. ×：Indicates that the content of hazardous substances or elements exceeding the SJ/T11363-2006 Standard limit requirements.									

6.2、Notion

Recommended carefully reading this information before the use of this product；

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